

MURHF860CT

Switch-mode Power Rectifier

These state-of-the-art Switch-mode power rectifiers are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 35 Nanosecond Recovery Times
- 150°C Operating Junction Temperature
- Electrically Isolated. No Isolation Hardware Required
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- This is a Pb-Free Package*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max for 10 Seconds

MAXIMUM RATINGS (Per Leg)

| Rating | Symbol | Value | Unit |
|--|---------------------------------|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V_{RRM} V_{RWM} V_R | 600 | V |
| Average Rectified Forward Current (Rated V_R , $T_C = 120^\circ\text{C}$) Total Device | $I_{F(AV)}$ | 4.0 8.0 | A |
| Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, $T_C = 120^\circ\text{C}$) | I_{FM} | 16 | A |
| Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | I_{FSM} | 100 | A |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | -65 to +150 | °C |

THERMAL CHARACTERISTICS (Per Leg)

| Rating | Symbol | Value | Unit |
|--|-----------------|-------|------|
| Max Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 4.1 | °C/W |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

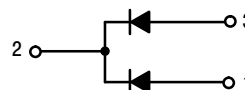
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



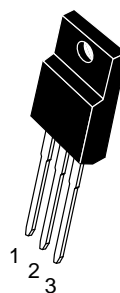
ON Semiconductor®

www.onsemi.com

ULTRAFAST RECTIFIER 8.0 AMPERES, 600 VOLTS



MARKING DIAGRAM



ISOLATED TO-220
CASE 221AH



A = Assembly Location
Y = Year
WW = Work Week
UH860 = Device Code
G = Pb-Free Package
AKA = Diode Polarity

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|---------------------|---------------|
| MURHF860CTG | TO-220 (Pb-Free) | 50 Units/Rail |

MURHF860CT

ELECTRICAL CHARACTERISTICS (Per Leg)

| Characteristic | Symbol | Value | Unit |
|---|----------|------------|---------------|
| Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 4.0\text{ A}$, $T_C = 150^\circ\text{C}$) ($i_F = 4.0\text{ A}$, $T_C = 25^\circ\text{C}$) | v_F | 2.5 2.8 | V |
| Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 150^\circ\text{C}$) (Rated DC Voltage, $T_C = 25^\circ\text{C}$) | i_R | 500 10 | μA |
| Maximum Reverse Recovery Time ($I_F = 1.0\text{ A}$, $di/dt = 50\text{ A}/\mu\text{s}$) | t_{rr} | 35 | ns |

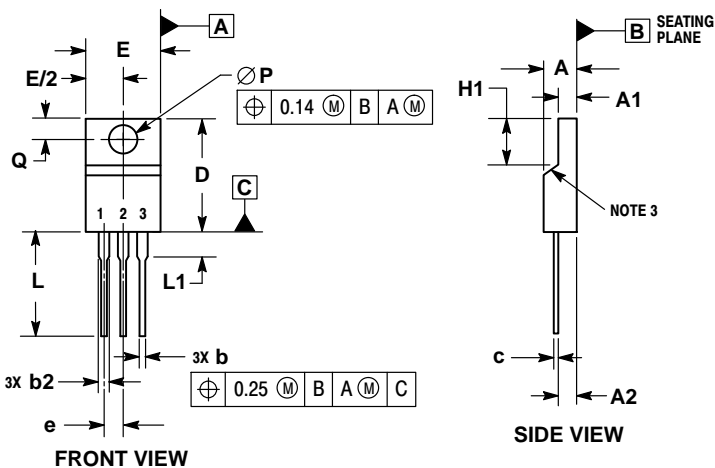
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

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PACKAGE DIMENSIONS

TO-220 FULLPACK, 3-LEAD CASE 221AH ISSUE F

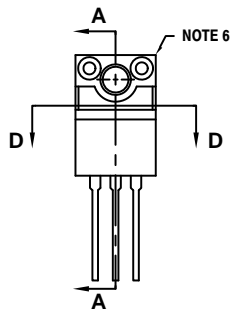


FRONT VIEW

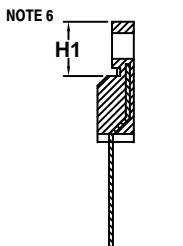
SIDE VIEW



SECTION D-D



ALTERNATE CONSTRUCTION



SECTION A-A

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR UNCONTROLLED IN THIS AREA.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.
6. CONTOURS AND FEATURES OF THE MOLDED PACKAGE BODY MAY VARY WITHIN THE ENVELOPE DEFINED BY DIMENSIONS A1 AND H1 FOR MANUFACTURING PURPOSES.

| DIM | MILLIMETERS | |
|-----|-------------|-------|
| | MIN | MAX |
| A | 4.30 | 4.70 |
| A1 | 2.50 | 2.90 |
| A2 | 2.50 | 2.90 |
| b | 0.54 | 0.84 |
| b2 | 1.10 | 1.40 |
| c | 0.49 | 0.79 |
| D | 14.70 | 15.30 |
| E | 9.70 | 10.30 |
| e | 2.54 BSC | |
| H1 | 6.60 | 7.10 |
| L | 12.50 | 14.73 |
| L1 | --- | 2.80 |
| P | 3.00 | 3.40 |
| Q | 2.80 | 3.20 |

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